

SEMICONDUCTOR TECHNICAL DATA

KDV174 SILICON EPITAXIAL PIN DIODE

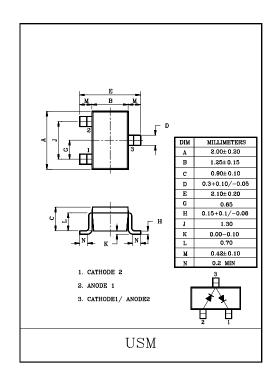
VHF~UHF BAND RF ATTENUATOR APPLICATION. AGC FOR AM/FM TUNER.

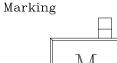
FEATURES

- Low Capacitance : C_T =0.25[pF] (TYP.). • Low Series Resistance : r_S =7[Ω] (TYP.).
- · Designed for Low Inter Modulation.

MAXIMUM RATINGS(Ta=25℃)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	$V_{ m R}$	50	V
Forward Current	I_{F}	50	mA
Junction Temperature	Tj	150	$^{\circ}$
Storage Temperature Range	T_{stg}	-55~150	$^{\circ}$





ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Voltage	V_{R}	I _R =10μA	50	=	=	V
Reverse Current	$ m I_R$	V_R =50 V	-	=	0.1	μΑ
Forward Voltage	$ m V_{F}$	I _F =50mA	-	0.95	-	V
Total Capacitance	C_{T}	V_R =50V, f=1MHz	=	0.25	=	pF
Series Resistance	$r_{\rm s}$	I _F =10mA, f=100MHz	=	7.0	-	Ω

